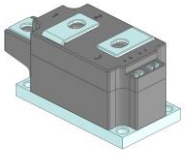
IXYS

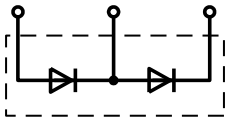
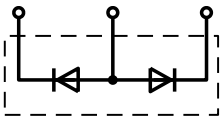
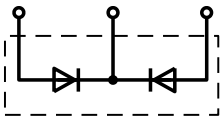


Date: 20.08.2015

Data Sheet Issue: 1

Diode Modules MD#275

Absolute Maximum Ratings

V_{RRM} V_{DRM} [V]	 MDD	 MDA	 MDK
3000	275-30N3	275-30N3	275-30N3
3600	275-36N3	275-36N3	275-36N3

	VOLTAGE RATINGS	MAXIMUM LIMITS	UNITS
V_{RRM}	Repetitive peak reverse voltage [1]	3000-3600	V
V_{RSM}	Non-repetitive peak reverse voltage [1]	3100-3700	V

	OTHER RATINGS	MAXIMUM LIMITS	UNITS
$I_{F(AV)M}$	Maximum average forward current, T_C = 85°C [2]	290	A
$I_{F(AV)M}$	Maximum average forward current. T_C = 100°C [2]	245	A
$I_{F(RMS)M}$	Nominal RMS forward current, T_C = 55°C [2]	580	A
$I_{F(d.c.)}$	D.C. forward current, T_C = 55°C	510	A
I_{FSM}	Peak non-repetitive surge t_p = 10 ms, V_{RM} = 60%V_{RRM} [3]	4.5	kA
I_{FSM2}	Peak non-repetitive surge t_p = 10 ms, $V_{RM} \leq$ 10V [3]	5.0	kA
I^2t	I^2t capacity for fusing t_p = 10 ms, V_{RM} = 60%V_{RRM} [3]	101	kA^2s
I^2t	I^2t capacity for fusing t_p = 10 ms, $V_{RM} \leq$ 10 V [3]	125	kA^2s
V_{ISOL}	Isolation Voltage [4]	3000	V
$T_{vj\ op}$	Operating temperature range	-40 to +150	°C
T_{stg}	Storage temperature range	-40 to +150	°C

Notes:

1) De-rating factor of 0.13% per °C is applicable for T_{vj} below 25°C.
2) Single phase; 50 Hz, 180° half-sinewave.
3) Half-sinewave, 150°C T_{vj} initial.
4) AC RMS voltage, 50 Hz, 1min test

Characteristics

	PARAMETER	MIN.	TYP.	MAX.	TEST CONDITIONS [1]	UNITS
V_{FM}	Maximum peak forward voltage	-	-	2.00	I_{TM} = 785 A, T_{VJ} = 25°C	V
V_{T0}	Threshold voltage	-	-	0.90		V
r_T	Slope resistance	-	-	1.57		mΩ
I_{RRM}	Peak reverse current	-	-	30	Rated V_{RRM}	mA
R_{thJC}	Thermal resistance, junction to case	-	0.1100	-	Single Arm	K/W
		-	0.0550	-	Whole Module	K/W
R_{thCH}	Thermal resistance, case to heatsink	-	0.040	-	Single Arm	K/W
		-	0.020	-	Whole Module	K/W
F_1	Mounting force (to heatsink)	-	6.00	-		Nm
F_2	Mounting force (to terminals)	-	9.00	-	[2]	Nm
W_t	Weight	-	800	-		g

Notes:

1) Unless otherwise indicated T_{vj}=125°C.
2) Screws must be lubricated.

Notes on Ratings and Characteristics

1.0 Voltage Grade Table

Voltage Grade	V_{DRM} V_{RRM} V	V_{DSM} V_{RSM} V	V_D V_R DC V
30	3000	3100	1750
36	3600	3700	1900

2.0 Extension of Voltage Grades

This report is applicable to other voltage grades when supply has been agreed by Sales/Production.

3.0 De-rating Factor

A blocking voltage de-rating factor of 0.13%/°C is applicable to this device for T_{vj} below 25°C.

4.0 Repetitive dv/dt

Standard dv/dt is 1000V/µs.

5.0 Snubber Components

When selecting snubber components, care must be taken not to use excessively large values of snubber capacitor or excessively small values of snubber resistor. Such excessive component values may lead to device damage due to the large resultant values of snubber discharge current. If required, please consult the factory for assistance.

6.0 Computer Modelling Parameters

6.1 Thyristor Dissipation Calculations

$$I_{AV} = \frac{-V_{T0} + \sqrt{V_{T0}^{\,2} + 4 \cdot ff^2 \cdot r_T \cdot W_{AV}}}{2 \cdot ff^2 \cdot r_T}$$

and:

$$W_{AV} = \frac{\Delta T}{R_{th}}$$

$$\Delta T = T_{j\max} - T_C$$

Where V_{T0} = 0.9 V, r_T = 1.57 mΩ.

R_{th} = Supplementary thermal impedance, see table below and

ff = Form factor, see table below.

Supplementary Thermal Impedance							
Conduction Angle	30°	60°	90°	120°	180°	270°	d.c.
Square wave	3.46	2.45	2	1.73	1.41	1.15	1
Sine wave	3.98	2.78	2.22	1.88	1.57		

Form Factors							
Conduction Angle	30°	60°	90°	120°	180°	270°	d.c.
Square wave	3.464	2.449	2	1.732	1.414	1.149	1
Sine wave	3.98	2.778	2.22	1.879	1.57		

6.2 D.C. Thermal Impedance Calculation

$$r_t = \sum_{p=1}^{p=n} r_p \cdot \left(1 - e^{\frac{-t}{\tau_p}}\right)$$

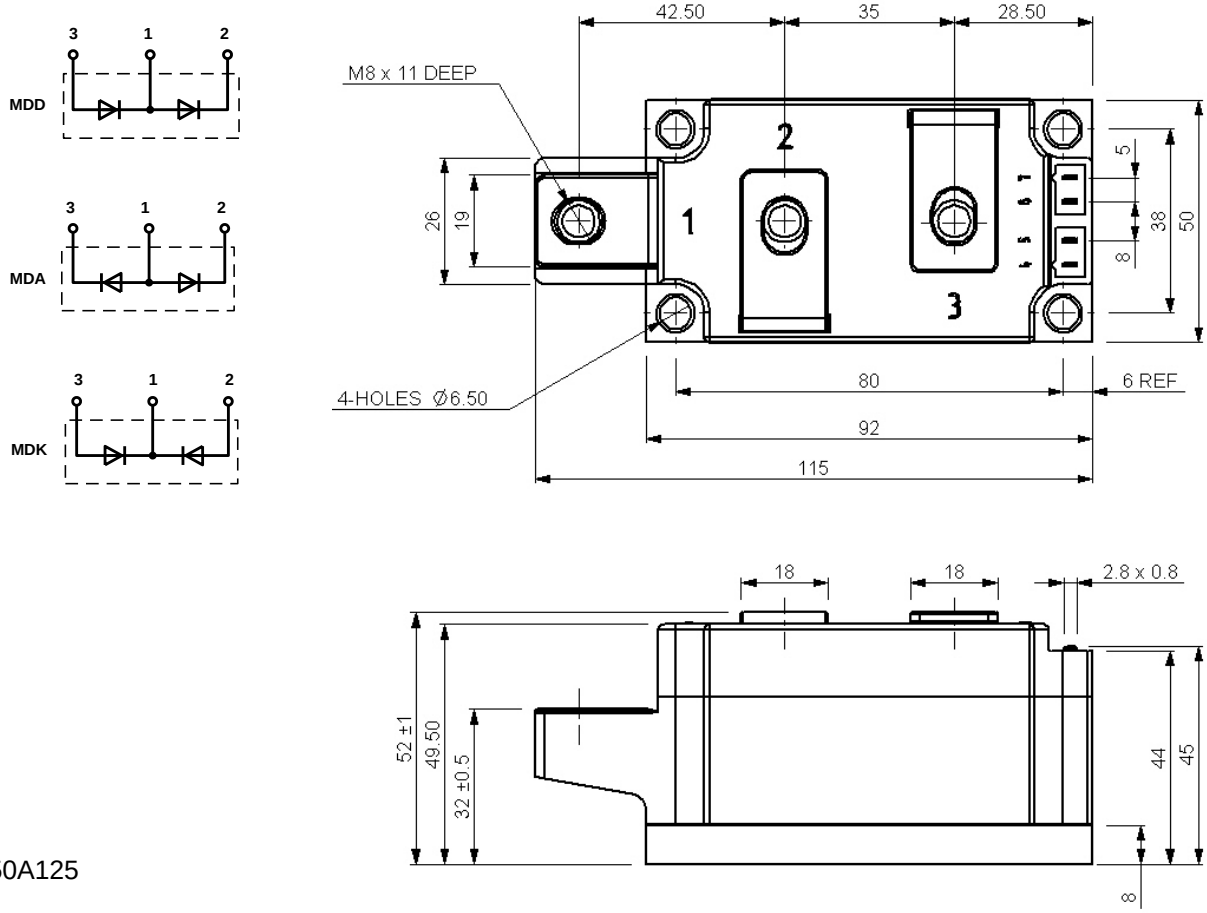
Where *p = 1* to *n and:*

n = number of terms in the series
t = Duration of heating pulse in seconds
r_t = Thermal resistance at time t
r_p = Amplitude of p_{th} term
τ_p = Time Constant of r_{th} term

The coefficients for this device are shown in the table below:

D.C.						
Term	1	2	3	4	5	6
r_p	0.1293	0.01314	0.02771	-0.05535	0.0528	0.002749
τ_p	2.823	1.393	0.3322	0.0611	0.05731	0.002713

Outline Drawing & Ordering Information



ORDERING INFORMATION (Please quote 11 digit code as below)					
M	**D#**	**275**	**♦♦**	**N**	**3**
Fixed Type Code	Configuration code DD, DA or DK	Fixed Type Code	Voltage code V_{RRM}/100 30-36	Standard Diode	Fixed Version Code

Typical order code: MDD275-30N3– MDD configuration, 3000V V_{RRM}

IXYS Semiconductor GmbH
Edisonstraße 15
D-68623 Lampertheim
Tel: +49 6206 503-0
Fax: +49 6206 503-627
E-mail: marcom@ixys.de

IXYS UK Westcode Ltd
Langley Park Way, Langley Park,
Chippenham, Wiltshire, SN15 1GE.
Tel: +44 (0)1249 444524
Fax: +44 (0)1249 659448
E-mail: sales@ixysuk.com

IXYS Corporation
1590 Buckeye Drive
Milpitas CA 95035-7418
Tel: +1 (408) 547 9000
Fax: +1 (408) 496 0670
E-mail: sales@ixys.net

IXYS Long Beach, Inc
IXYS Long Beach, Inc
2500 Mira Mar Ave, Long Beach
CA 90815
Tel: +1 (562) 296 6584
Fax: +1 (562) 296 6585
E-mail: service@ixyslongbeach.com

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